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\*\* CONTINUING DATA \*\*\*\*\* *None S.W.S.*

\*\* FOREIGN APPLICATIONS \*\*\*\*\* *S.W.S.*  
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## IF REQUIRED, FOREIGN FILING LICENSE GRANTED

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35 USC 119 (a-d) conditions met	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after <i>allowance</i>		DRAWING 3	CLAIMS 12	CLAIMS 1
Verified and Acknowledged  Examiner's Signature	<i>S.W.S.</i>	Initials			

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## TITLE

Method for manufacturing gallium nitride (GaN) based single crystalline substrate that includes separating from a growth substrate

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